

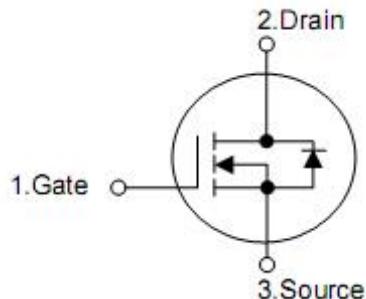
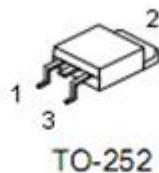
## 1. Features

- RDS(on)=3.1mΩ@ VGS=10V
- Uses CRM(CQ) advanced Trench MOS technology
- Extremely low on-resistance  $R_{DS(on)}$
- Excellent QgxR<sub>DS(on)</sub> product(FOM)
- Qualified according to JEDEC criteria

## 2. Applications

- Motor control and drive
- Battery management
- UPS (Uninterruptible Power Supplies)

## 3. Symbol



Pin	Function
1	Gate
2	Drain
3	Source

## 4. Ordering information

Part Number	Package	Brand
KND3203B	TO-252	KIA

## 5. Absolute maximum ratings

( $T_A=25^\circ\text{C}$ ,unless otherwise noted)

Parameter	Symbol	Rating	Units
Drain-source voltage	$V_{DS}$	30	V
Continuous drain current	$I_D$	100	
		80	A
		72	A
Pulse drain current ( $T_c = 25^\circ\text{C}$ , $t_p$ limited by $T_{jmax}$ )	$I_{DP}$	320	A
Avalanche energy, single pulse ( $L=0.5\text{mH}$ )	$E_{AS}$	90	mJ
Gate-Source voltage	$V_{GS}$	$\pm 20$	V
Power dissipation ( $T_c = 25^\circ\text{C}$ )	$P_{tot}$	101	W
Operating junction and storage temperature	$T_J, T_{STG}$	-55- 150	$^\circ\text{C}$

## 6. Thermal characteristics

Parameter	Symbol	Max	Unit
Thermal resistance, Junction-ambient	$R_{\theta JA}$	105	$^\circ\text{C/W}$
Thermal resistance, Junction-case	$R_{\theta JC}$	1.24	$^\circ\text{C/W}$

## 7. Electrical characteristics

( $T_A=25^\circ\text{C}$ ,unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Drain-source breakdown voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{DS}}=250\mu\text{A}$	30	-	-	V
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	1.3	1.8	2.3	V
Zero gate voltage drain current	$I_{\text{DSS}}$	$V_{\text{DS}}=30\text{V}, V_{\text{GS}}=0\text{V}, T_J=25^\circ\text{C}$	-	-	1	$\mu\text{A}$
		$V_{\text{DS}}=24\text{V}, V_{\text{GS}}=0\text{V}, T_J=125^\circ\text{C}$	-	-	10	
Gate-source leakage current	$I_{\text{GSS}}$	$V_{\text{GS}}=20\text{V}, V_{\text{DS}}=0\text{V}$	-	-	100	nA
Drain-source on-resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=10\text{V}, I_{\text{D}}=24\text{A}, T_J=25^\circ\text{C}$	-	3.1	4.0	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=20\text{A}$	-	4.7	7.0	
Forward transconductance	$g_{\text{fs}}$	$V_{\text{DS}}=5\text{V}, I_{\text{D}}=30\text{A}$	-	73	-	S
Input capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=30\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$	-	2340	-	$\text{pF}$
Output capacitance	$C_{\text{oss}}$		-	460	-	
Reverse transfer capacitance	$C_{\text{rss}}$		-	305	-	
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=15\text{V}, I_{\text{D}}=30\text{A}, R_{\text{G\_ext}}=3\Omega, V_{\text{GS}}=10\text{V}$	-	11	-	$\text{nS}$
Rise time	$t_{\text{r}}$		-	102	-	
Turn-off delay time	$t_{\text{d}(\text{off})}$		-	34	-	
Fall time	$t_{\text{f}}$		-	95	-	
Total gate charge	$Q_{\text{g}}$	$V_{\text{DS}}=15\text{V}, V_{\text{GS}}=10\text{V}$ $I_{\text{D}}=30\text{A}, f=1\text{MHz}$	-	50	-	$\text{nC}$
Gate-source charge	$Q_{\text{gs}}$		-	9.5	-	
Gate-drain charge	$Q_{\text{gd}}$		-	13.2	-	
Gate resistance	$R_{\text{g}}$	$V_{\text{DS}}=0\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$	-	1.4	-	$\Omega$
Body Diode forward voltage	$V_{\text{SD}}$	$V_{\text{GS}}=0\text{V}, I_{\text{SD}}=200\text{A}$	-	-	1.3	V
Body Diode Reverse Recovery Time	$t_{\text{rr}}$	$I_{\text{F}}=30\text{A},$ $di/dt=100\text{A}/\mu\text{s}$	-	21	-	$\text{nS}$
Body Diode Reverse Recovery charge	$Q_{\text{rr}}$		-	12	-	$\text{nC}$

## 8. Test circuits and waveforms

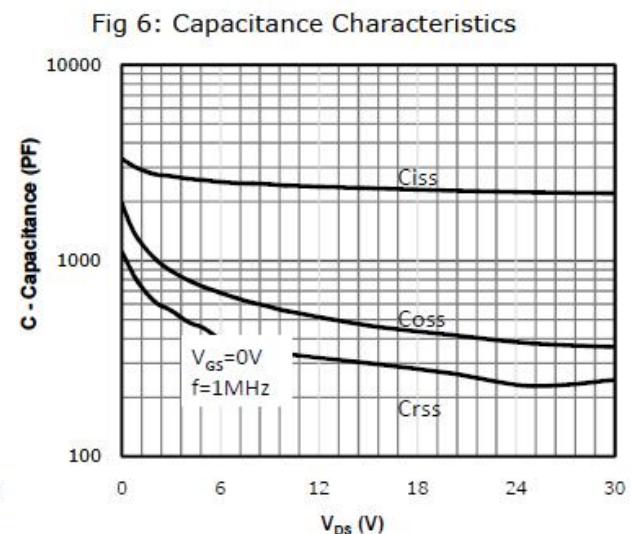
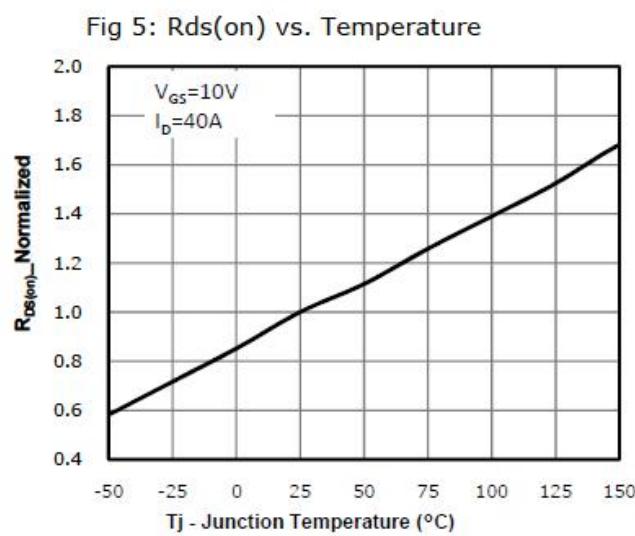
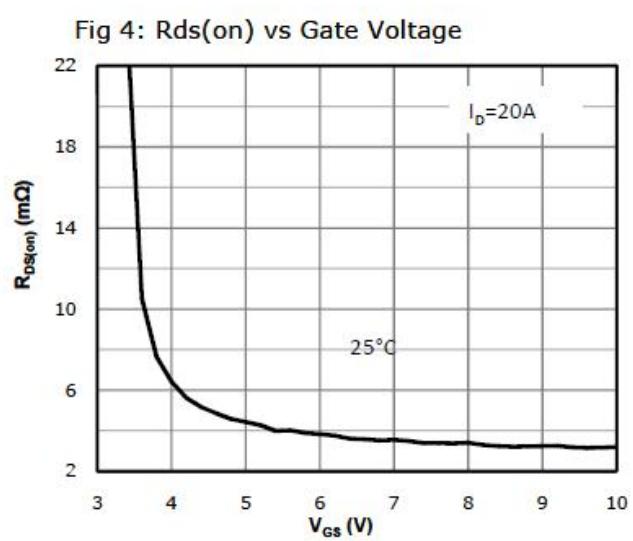
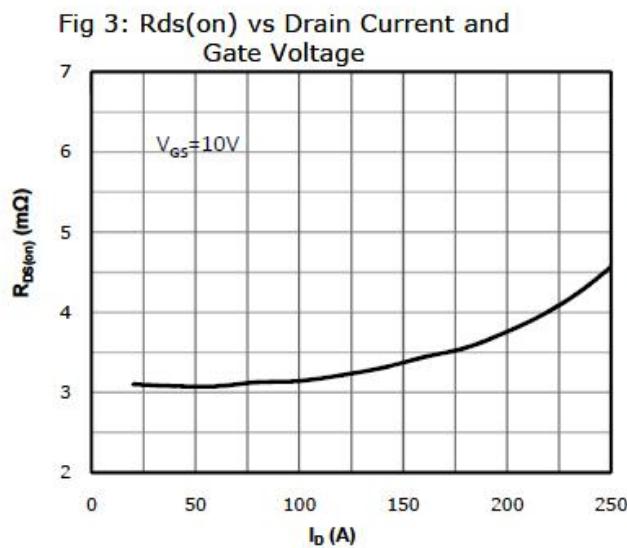
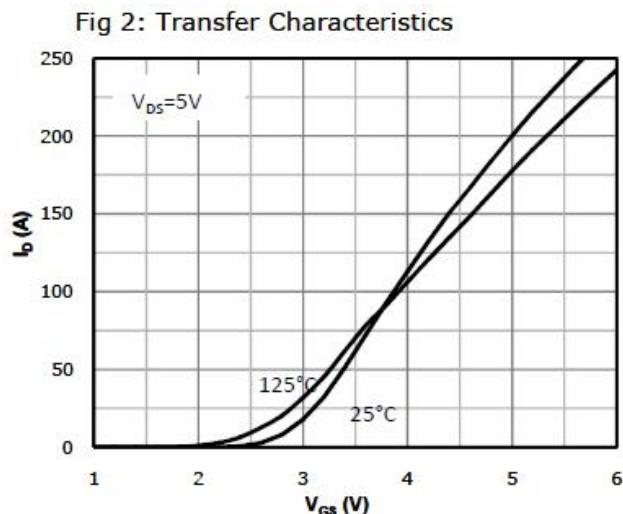
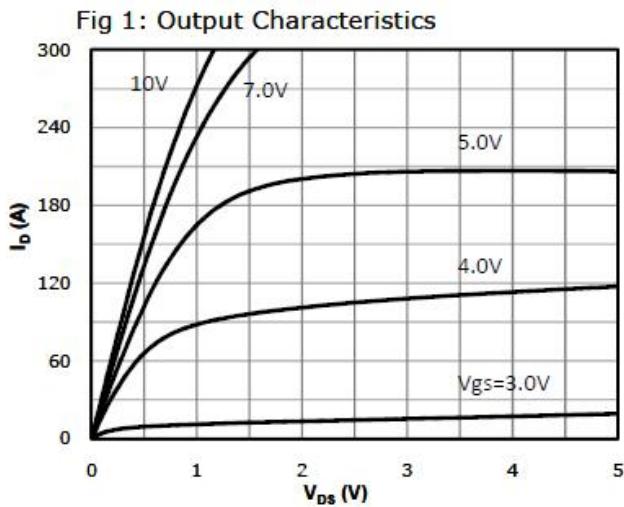


Fig 7: Gate Charge Characteristics

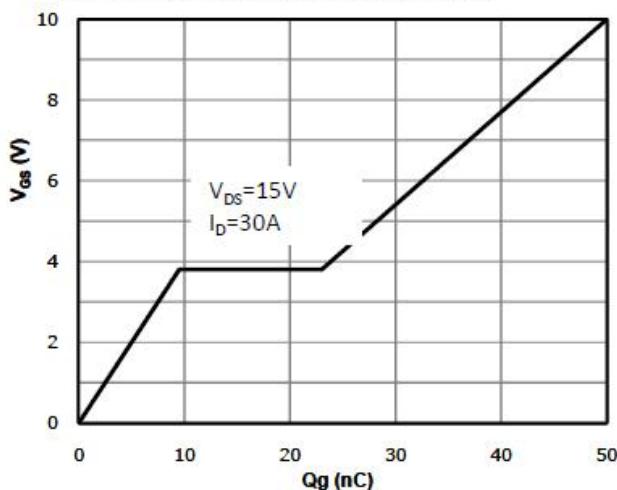


Fig 8: Body-diode Forward Characteristics

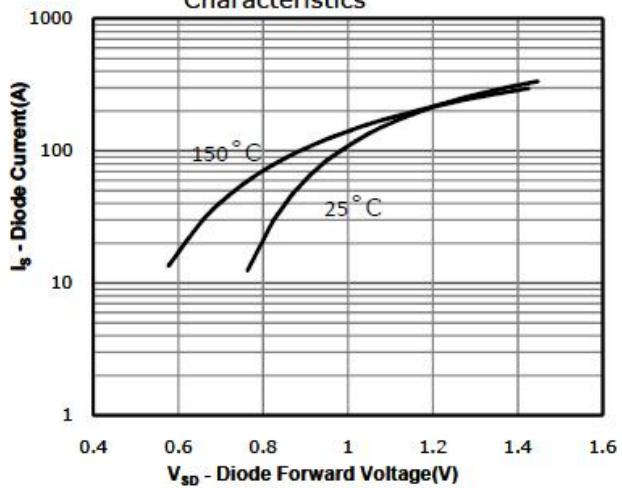


Fig 9: Power Dissipation

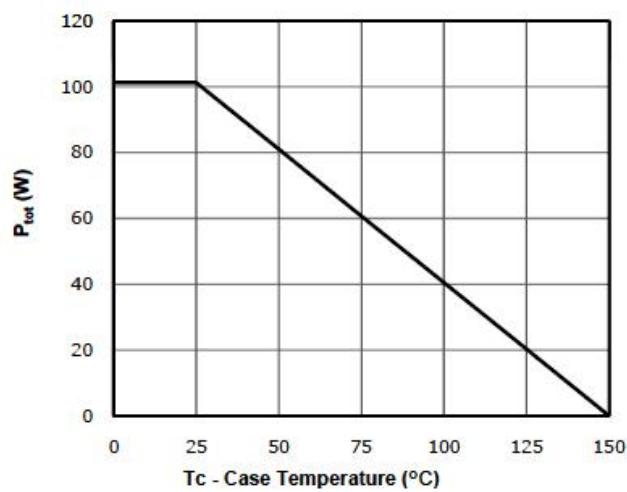


Fig 10: Drain Current Derating

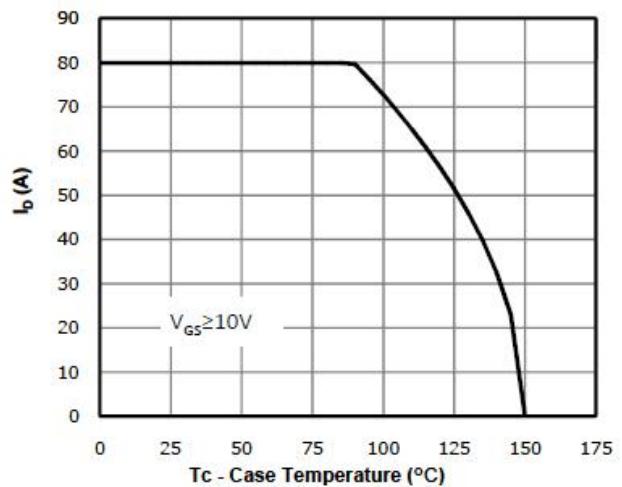


Fig 11: Safe Operating Area

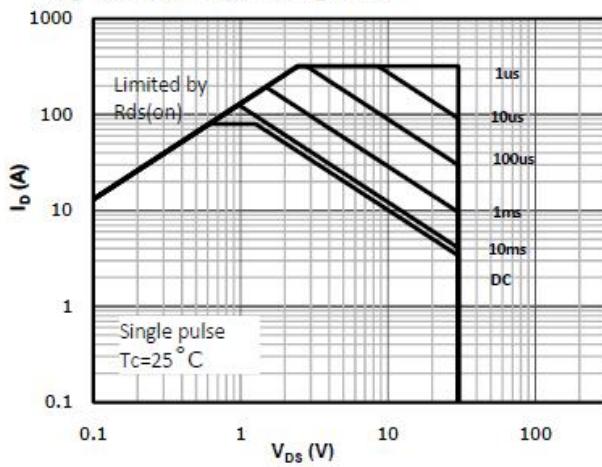
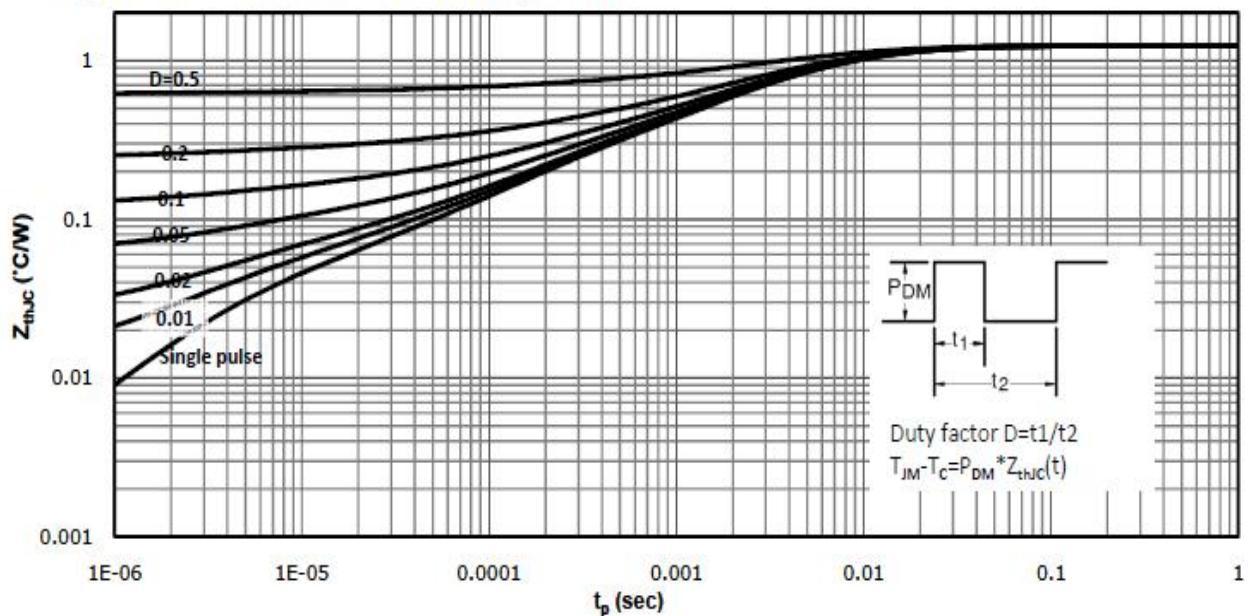


Fig 12: Max. Transient Thermal Impedance



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